

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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**Phase-out/Discontinued**

**P-CHANNEL POWER MOS FET ARRAY  
SWITCHING  
INDUSTRIAL USE**

**DESCRIPTION**

The μPA1523B is P-channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

**FEATURES**

- Full Mold Package with 4 Circuits
- -4 V driving is possible
- Low On-state Resistance  
 $R_{DS(on)1} = 0.8 \Omega \text{ MAX. (@ } V_{GS} = -10 \text{ V, } I_D = -1 \text{ A)}$   
 $R_{DS(on)2} = 1.3 \Omega \text{ MAX. (@ } V_{GS} = -4 \text{ V, } I_D = -1 \text{ A)}$
- Low Input Capacitance  $C_{iss} = 190 \text{ pF TYP.}$

**ORDERING INFORMATION**

Type Number	Package
μPA1523BH	10 Pin SIP

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C)**

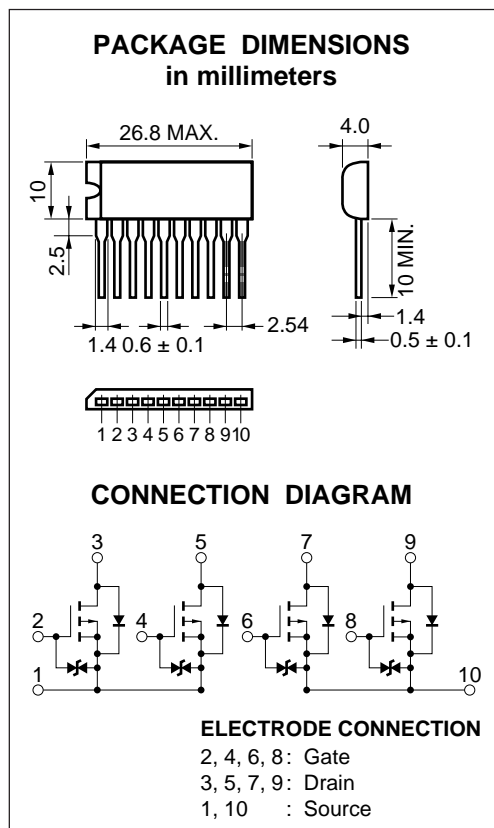
Drain to Source Voltage (V <sub>GS</sub> = 0)	V <sub>DSS</sub>	-60	V
Gate to Source Voltage (V <sub>DS</sub> = 0)	V <sub>GSS(AC)</sub>	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±2.0	A/unit
Drain Current (pulse)	I <sub>D(pulse)</sub> *1	±8.0	A/unit
Total Power Dissipation	P <sub>T1</sub> *2	28	W
Total Power Dissipation	P <sub>T2</sub> *3	3.5	W
Channel Temperature	T <sub>CH</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to + 150	°C
Single Avalanche Current	I <sub>AS</sub> *4	-2.0	A
Single Avalanche Energy	E <sub>AS</sub> *4	0.4	mJ

\*1 PW ≤ 10 μs, Duty Cycle ≤ 1%

\*2 4 Circuits, T<sub>C</sub> = 25 °C

\*3 4 Circuits, T<sub>A</sub> = 25 °C

\*4 Starting T<sub>CH</sub> = 25 °C, V<sub>DD</sub> = -30 V, V<sub>GS</sub> = -20 V → 0, R<sub>G</sub> = 25 Ω, L = 100 μH



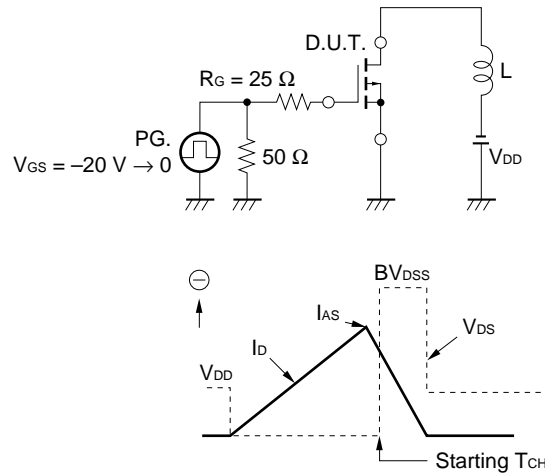
Build-in Gate Diodes are for protection from static electricity in handling.  
 In case high voltage over V<sub>GSS</sub> is applied, please append gate protection circuits.

The information in this document is subject to change without notice.

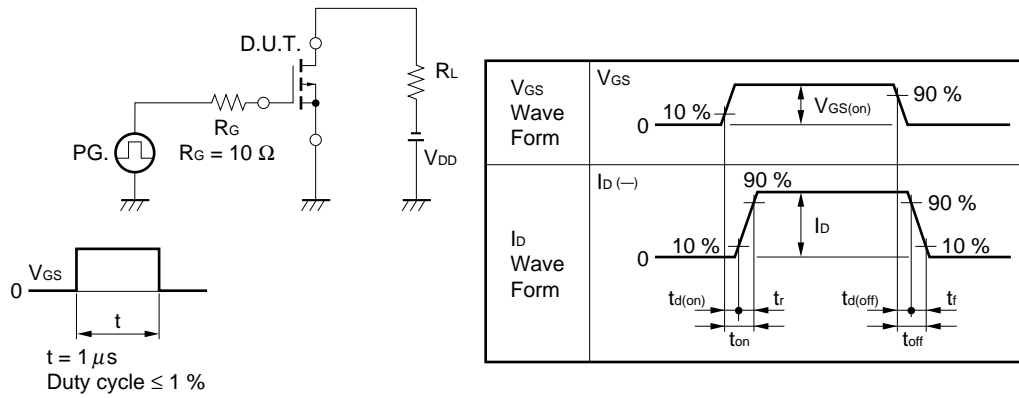
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)**

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> = -60 V, V <sub>GS</sub> = 0			-10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0			±10	μA
Gate Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.0 mA	-1.0		-2.0	V
Forward Transfer Admittance	Y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.0 A	0.8			S
Drain to Source ON-Resistance	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -1.0 A		0.5	0.8	Ω
Drain to Source ON-Resistance	R <sub>DS(on)2</sub>	V <sub>GS</sub> = -4.0 V, I <sub>D</sub> = -1.0 A		0.8	1.3	Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0, f = 1.0 MHz		190		pF
Output Capacitance	C <sub>oss</sub>			115		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			43		pF
Turn-on Delay Time	t <sub>d(on)</sub>	I <sub>D</sub> = -1.0 A, V <sub>GS(on)</sub> = -10 V, V <sub>DD</sub> ≐ -30 V, R <sub>L</sub> = 30 Ω		8		ns
Rise Time	t <sub>r</sub>			53		ns
Turn-off Delay Time	t <sub>d(off)</sub>			400		ns
Fall Time	t <sub>f</sub>			230		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -2.0 A, V <sub>DD</sub> = -48 V		10		nC
Gate to Source Charge	Q <sub>GS</sub>			1.1		nC
Gate to Drain Charge	Q <sub>GD</sub>			3.5		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	I <sub>F</sub> = 2.0 A, V <sub>GS</sub> = 0		1.0		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.0 A, V <sub>GS</sub> = 0, di/dt = 50 A/μs		180		ns
Reverse Recovery Charge	Q <sub>rr</sub>			250		nC

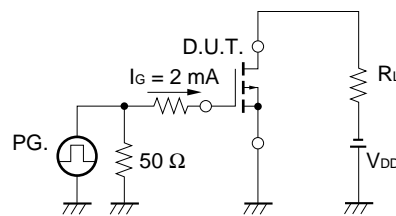
**Test Circuit 1 Avalanche Capability**



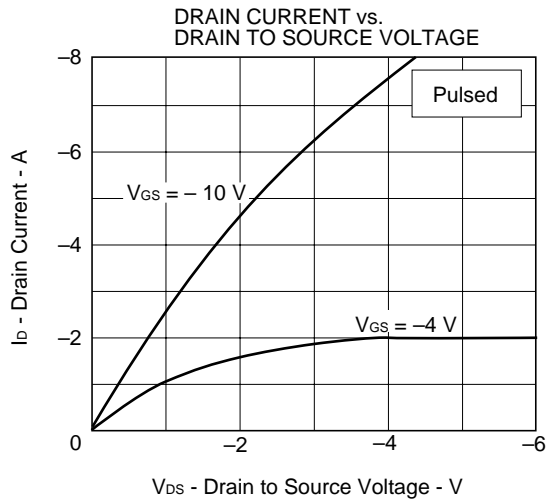
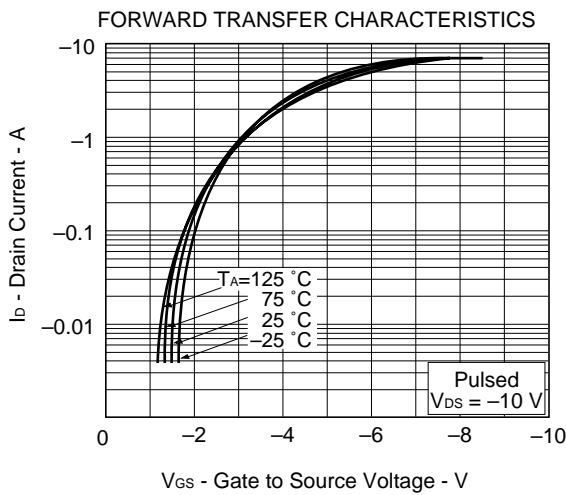
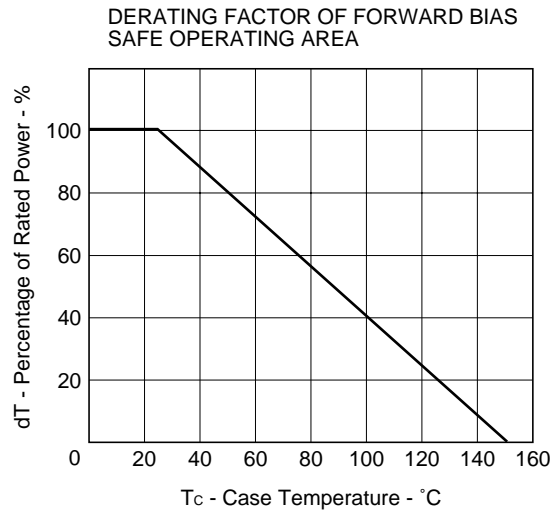
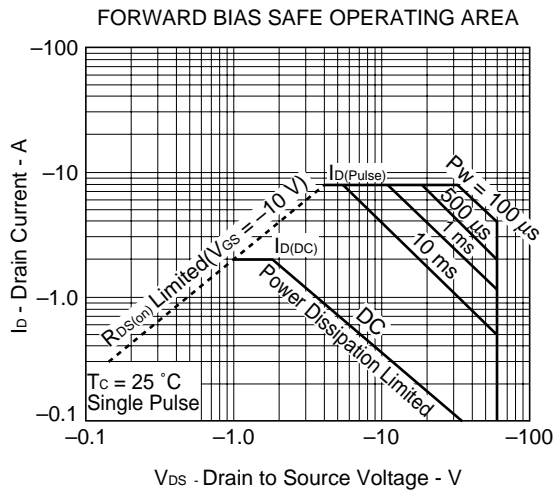
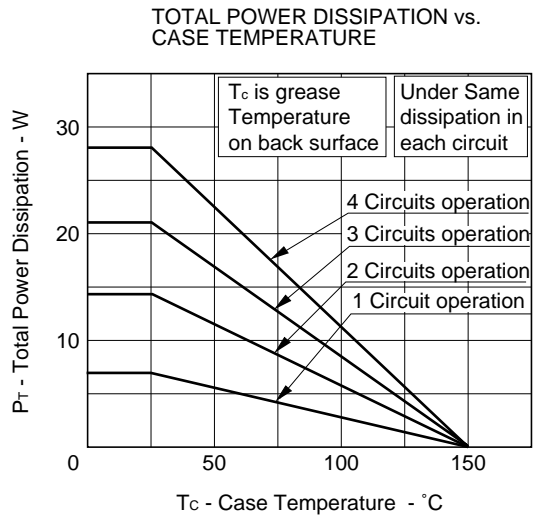
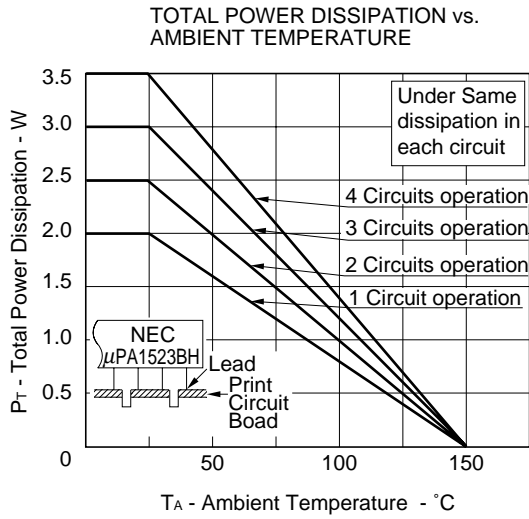
**Test Circuit 2 Switching Time**



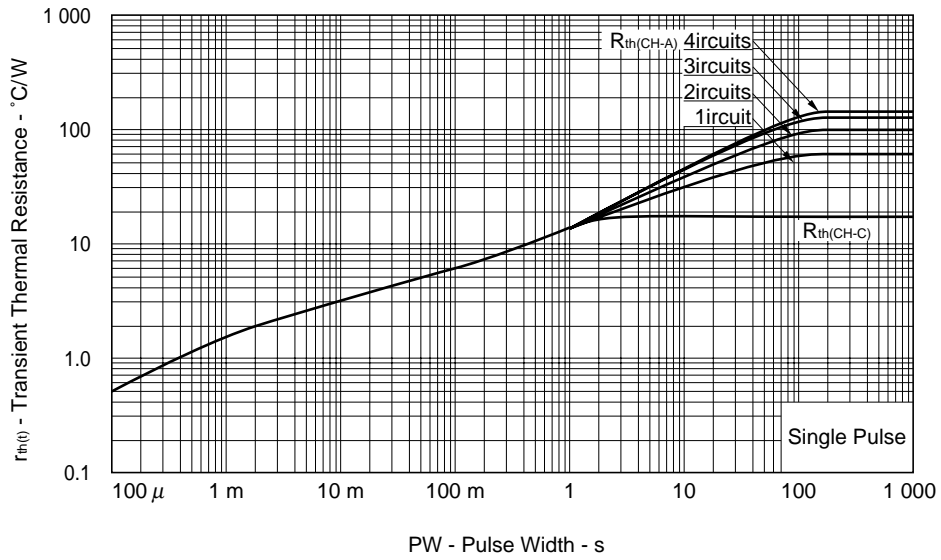
**Test Circuit 3 Gate Charge**



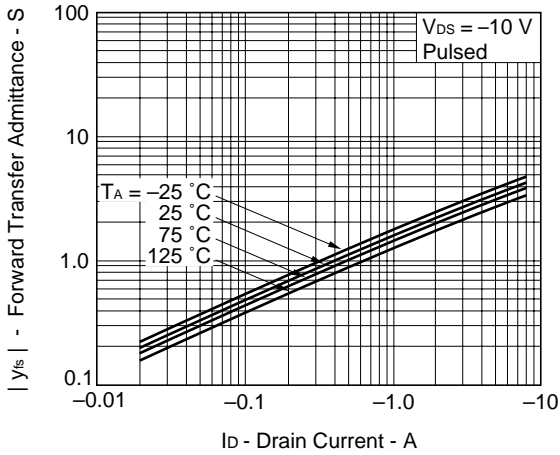
TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )



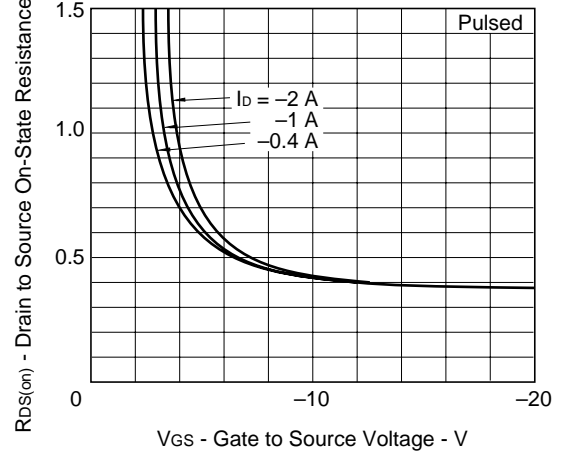
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



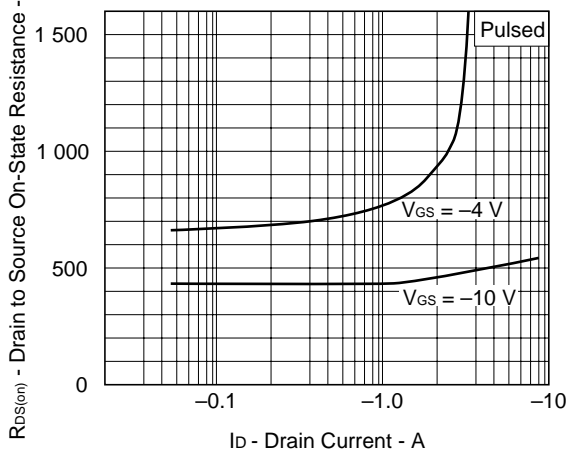
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



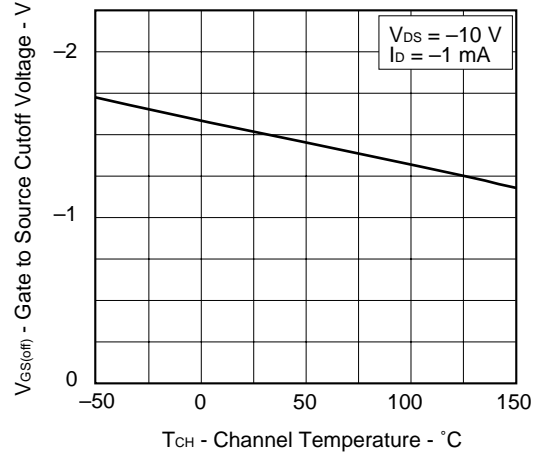
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

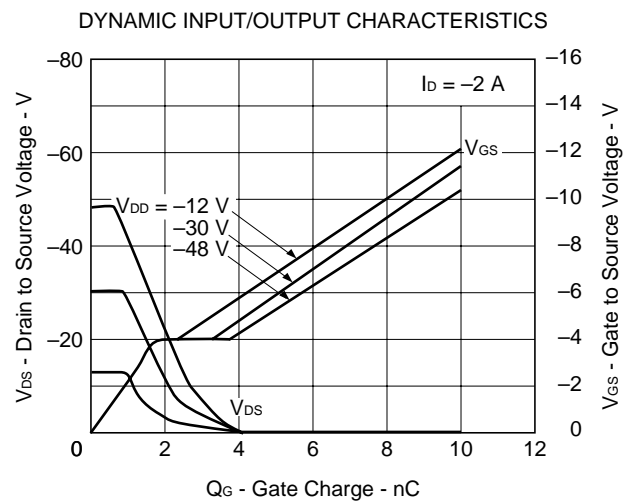
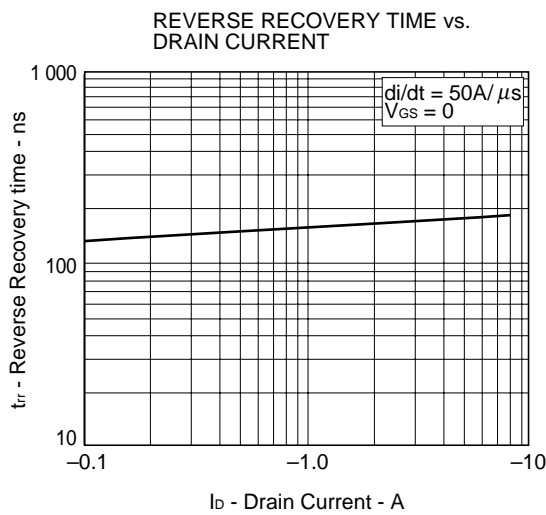
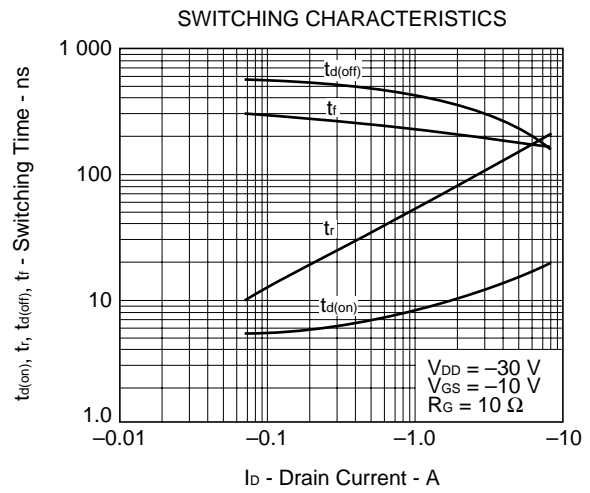
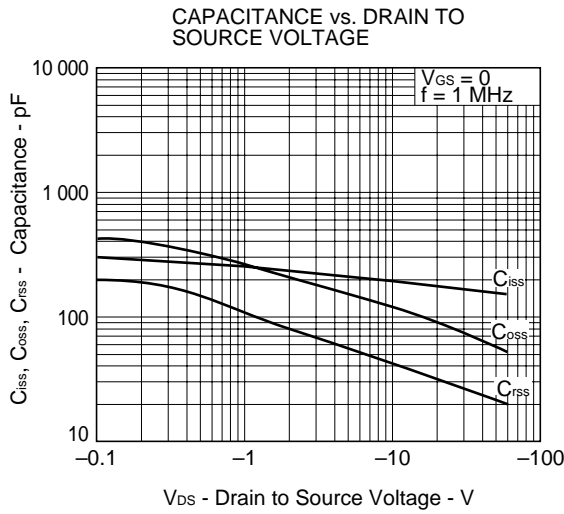
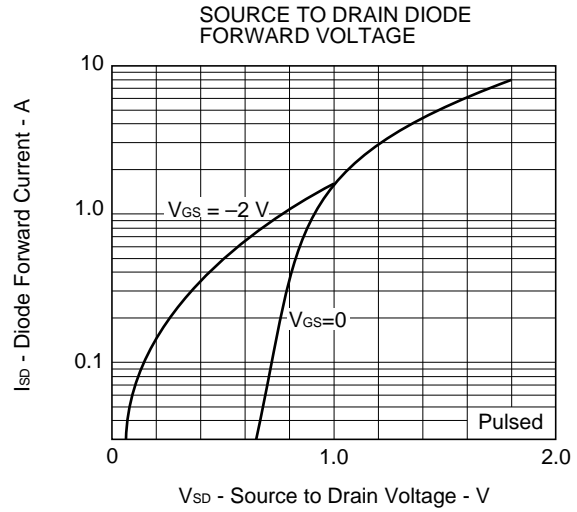
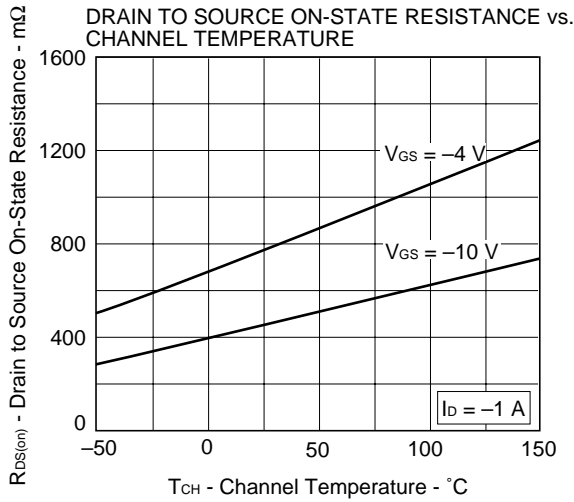


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

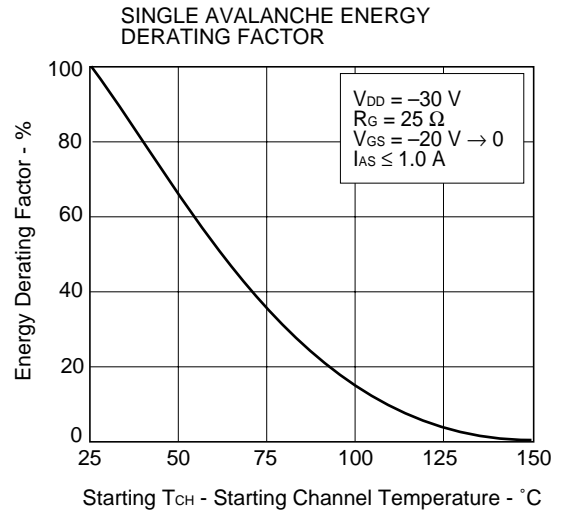
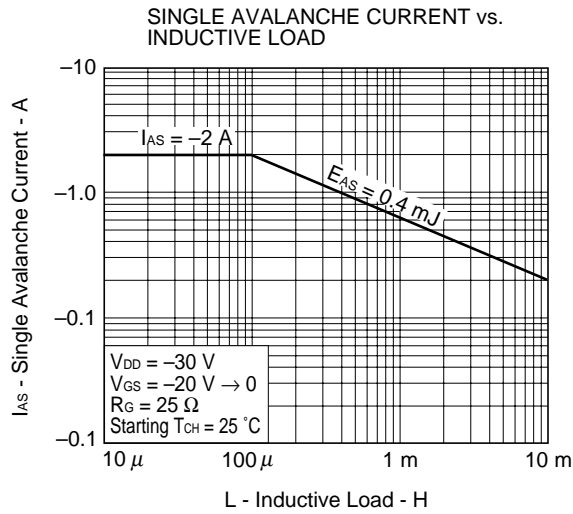


GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE









**REFERENCE**

Document Name	Document No.
NEC semiconductor for device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Semiconductor device package manual	C10943X
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E
Power MOS FET features and application switching power supply	TEA-1034
Application circuits using Power MOS FET	TEA-1035
Safe operating area of Power MOS FET	TEA-1037

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